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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Raul-Adrian Cernea and Yan Li
Title: Non-Volatile Memory and Method With Improved Sensing
Application No.: 10/665,828 Filing Date: September 17, 2003
Examiner: David Lam Group Art Unit: 2818
Docket No.: SNDK.268US1 Conf. No.: 6022

Certificate of Mailing Under 37 CFR 1.8

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on May 26, 2004

Signature *Thaegut*

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicant(s) call(s) the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application.

This application has a filing date after June 30, 2003. Copies of the U.S Patent(s) and U.S. Published Patent Application(s) documents listed on the accompanying Form PTO-1449 are not enclosed.

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a representation that a search has been made (other than as indicated by any cited

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Attorney Docket No.:
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document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

This information disclosure statement is submitted under 37 C.F.R. § 1.97(c). A check including \$180.00 for the information disclosure statement fee under 37 C.F.R. § 1.17(p), is enclosed. The Commissioner is authorized, however, to charge any fee that may be required, or to credit any overpayment, against Deposit Account No. 502664. This form is being submitted in duplicate.

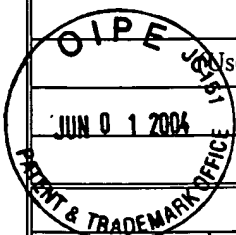
Respectfully submitted,


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May 26, 2004
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U.S. Department of Commerce, Patent and Trademark	Atty. Docket No.	Application No.
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	SNDK.268US1	10/665,828
	Applicant(s)	Conf. No.
(Use several sheets if necessary)	Raul-Adrian Cernea and Yan Li	6022
	Filing Date	Group
	September 17, 2003	2818



U.S. Patent Documents

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	1	4,785,427	Nov. 15, 1988	Young			
	2	5,093,806	Mar. 3, 1992	Tran			
	3	5,245,571	Sep. 14, 1993	Takahashi			
	4	5,595,924	Jan. 21, 1997	Yuan et al.			
	5	5,860,082	Jan. 12, 1999	Smith et al.			
	6	5,872,739	Feb. 16, 1999	Womack			
	7	5,949,720	Sep. 4, 1999	Brady			
	8	6,097,638	Aug. 1, 2000	Himeno et al.			

U.S. Published Patent Application Documents

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

Foreign Patent Documents

							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	9	1134746 A2	Sep. 19, 2001	Europe				
	10	WO 02/069340	Sep. 6, 2002	WIPO				

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

	11	International Search Report corresponding to PCT/US03/30133, International Searching Authority, European Patent Office, filed September 18, 2003, 4 pages
	12	Eitan et al., "NROM: A Novel Localized Trapping 2-Bit Nonvolatile Memory Cell," IEEE Electron Device Letters, vol. 21, no. 11, Nov. 2000, pp. 543-545

Examiner

Date Considered

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.